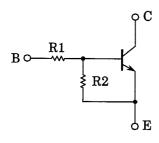
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2501,RN2502,RN2503 RN2504,RN2505,RN2506

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in SMV (super mini type with 5 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1501~RN1506

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2501	4.7	4.7
RN2502	10	10
RN2503	22	22
RN2504	47	47
RN2505	2.2	47
RN2506	4.7	47

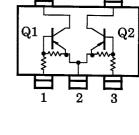
Unit: mm 1.9 ± 0.2 1. BASE 1 2. EMITTER (E) 3. BASE 2 (B2)4. COLLECTOR 2 (C2) 5. COLLECTOR 1 (C1) **JEDEC** EIAJ **TOSHIBA** 2-3L1A

Weight: 0.014g

Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN2501~2506	V _{CBO}	-50	V	
Collector-emitter voltage	KN2501*2500	V_{CEO}	-50	V	
Emitter base voltage	RN2501~2504	\/	-10	V	
	RN2505, 2506	V _{EBO}	-5		
Collector current		I _C	-100	mA	
Collector power dissipation	RN2501~2506	P _C *	300	mW	
Junction temperature	KIN2501~2506	Tj	150	°C	
Storage temperature range		Tstg	-55~150	°C	



^{*} Total rating

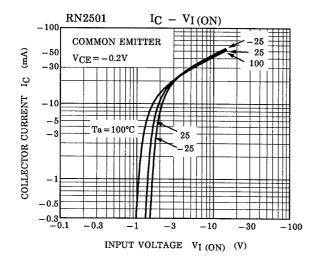


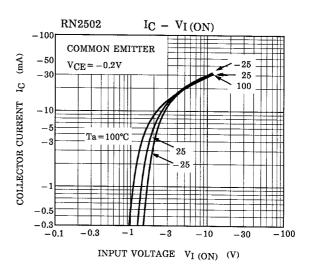
Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

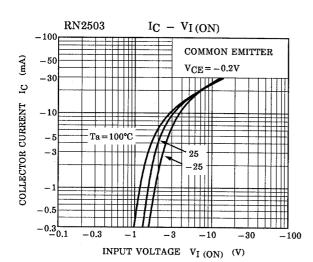
Characteristic		Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2501~2506	I _{CBO}	_	V _{CB} = -50V, I _E = 0	_	_	-100	nA
	KIN2301*2300	I _{CEO}	_	V _{CE} = -50V, I _B = 0	_	_	-500	
	RN2501	I _{EBO}	_	V _{EB} = −10V, I _C = 0	-0.82	_	-1.52	mA
	RN2502		_		-0.38	_	-0.71	
	RN2503		_		-0.17	_	-0.33	
Emitter cut-off current	RN2504		_		-0.082	_	-0.15	
	RN2505		_	V _{EB} = -5V, I _C = 0	-0.078	_	-0.145	
	RN2506		_		-0.074	_	-0.138	
	RN2501		_		30	_	_	
	RN2502		_		50	_	_	
DO summed main	RN2503	L	_	V _{CE} = -5V	70	_	_	
DC current gain	RN2504	h _{FE}	_	I _C = -10mA	80	_	_	_
	RN2505		_		80	_	_	
	RN2506		_		80	_	_	
Collector-emitter saturation voltage	RN2501~2506	V _{CE (sat)}	_	I _C = -5mA I _B = -0.25mA	_	-0.1	-0.3	٧
	RN2501	V _{I (ON)}	_	V _{CE} = -0.2V I _C = -5mA	-1.1	_	-2.0	2.4 3.0 5.0 1.1
	RN2502		_		-1.2	_	-2.4	
	RN2503		_		-1.3	_	-3.0	
Input voltage (ON)	RN2504		_		-1.5	_	-5.0	
	RN2505		_		-0.6	_	-1.1	
	RN2506		_		-0.7	_	-1.3	
land valtage (OFF)	RN2501~2504	V _{I (OFF)}	_	V _{CE} = -5V I _C = -0.1mA	-1.0	_	-1.5	V
Input voltage (OFF)	RN2505, 2506		_		-0.5	_	-0.8	
Translation frequency	RN2501~2506	f _T	_	V _{CE} = -10V I _C = -5mA	_	200	_	MHz
Collector output capacitance	RN2501~2506	C _{ob}	_	V _{CB} = -10V, I _E = 0 f = 1MHz	_	3	6	pF
	RN2501	R1	_	7 15.4 32.9	3.29	4.7	6.11	kΩ
	RN2502		_		7	10	13	
Input resistor	RN2503		_		15.4	22	28.6	
	RN2504		_		32.9	47	61.1	
	RN2505		_		2.2	2.86		
	RN2506		_		3.29	4.7	6.11	1
Resistor ratio	RN2501~2504	R1/R2	_	_	0.9	1.0	1.1	_
	RN2505		_		0.0421	0.0468	0.0515	
	RN2506		_		0.09	0.1	0.11	

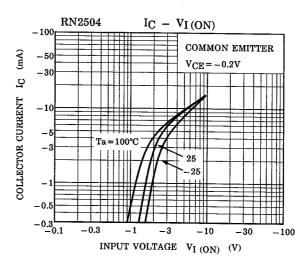
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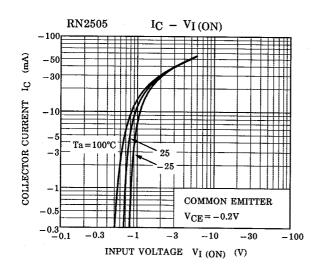
(Q1, Q2 Common)

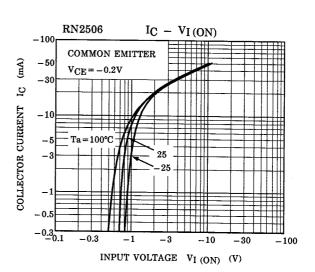






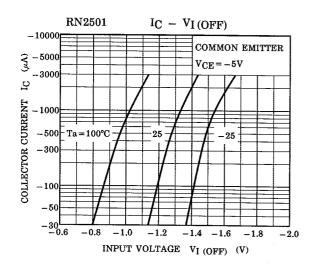


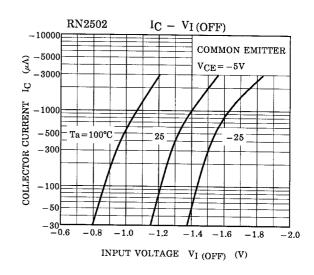


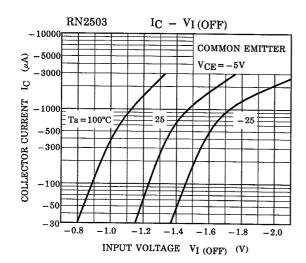


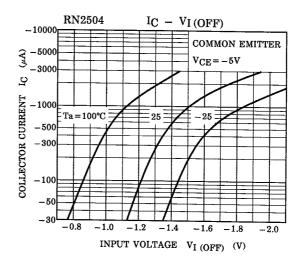
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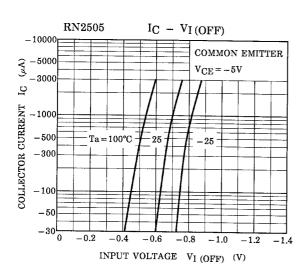
(Q1, Q2 Common)

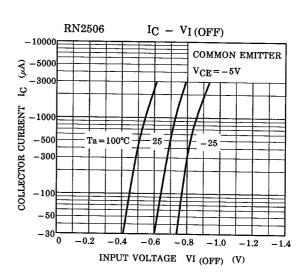




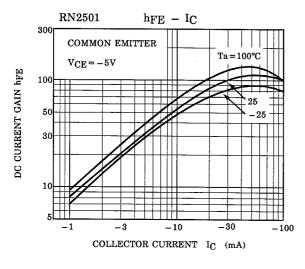


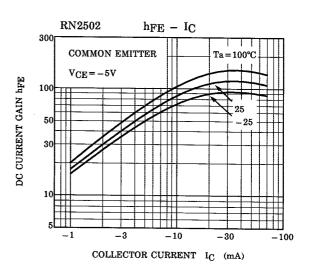


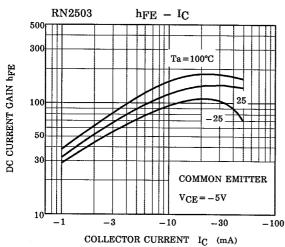


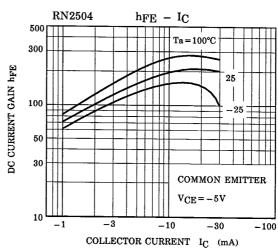


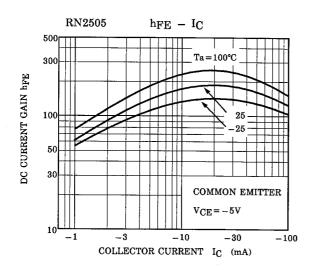
(Q1, Q2 Common)

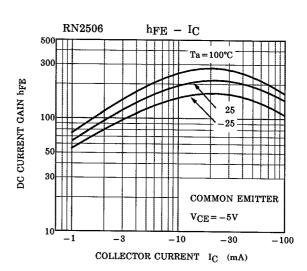












5

Type Name	Marking
RN2501	Type Name YA
RN2502	Type Name Y B
RN2503	Type Name YC
RN2504	Type Name Y D
RN2505	Type Name YE
RN2506	Type Name Y F

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000707EAA

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